

Curriculum Vitae

JIN-WEI SHI

Department of Electrical Engineering
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Interests ultrahigh speed/power photodiodes and avalanche photodiodes, high-speed vertical-cavity surface-emitting laser and photodiode for optical interconnect, light source and detector for FMCW LiDAR.

Education **B.S.**, Electrical Engineering, **National Taiwan University**, Taipei, Taiwan, 1998.6.
Ph.D., Electro-Optical Engineering, **National Taiwan University**, Taipei, Taiwan, 2002.6. Thesis: Metal-Semiconductor-Metal Traveling Wave Photodetectors Advisor: Chi-Kuang Sun

Experience **NATIONAL TAIWAN UNIVERSITY** **Taipei, TAIWAN**
Graduate Institute of Electro-Optical Engineering
Research Assistant 1998.8 –2002.7
Research topics cover design and modeling of ultra-high speed and high power traveling wave photodetector/photomixer, measurement of ultra-high speed device (E-O sampling), nonlinearity of low temperature grown GaAs based photodetector, and optoelectronic generation of sub-millimeter wave.

UNIVERSITY of CALIFORNIA **Santa Barbara, CA**
Department of Electrical and Computer Engineering
Visiting Scholar 2000.6- 2000.9 and 2001.2-2001.8
Research includes fabrication of ultrahigh speed and high power traveling wave photodetector/photomixer, photomixer array, membrane THz photomixer.

INDUS. TECH. RES. INS. **Hsinchu, TAIWAN**
Electronics Research & Service Organization
Consultant 2002/12~2003/8
Research includes Si/SiGe/SiC based optical communication systems on a single Si chip (SOC), high speed HPT, ultra-high gain-bandwidth product APD.

NATIONAL CENTRAL UNIVERSITY **Taoyuan, TAIWAN**
Department of Electrical Engineering
Assistant Professor 2003/8~2006/8
Associate Professor 2006/8 to 2012/01
Professor 2011/8- now
Research includes high-speed and high-power photodiode, THz photonic transmitter, electro-absorption modulator, Si/SiGe based avalanche photodiode, High-speed GaN based LED, High-Speed VCSEL, Infrared and visible white-light LED

UNIVERSITY of CALIFORNIA **Santa Barbara, CA**
Department of Electrical and Computer Engineering
Visiting Professor 2011/02-2012/02 and 2016/02-2017/02
Research includes Si photonic integrated circuit, sub-THz photonic transmitter-mixer, photonic wireless communication with ultra-high data rate.

Contributions Some of Prof. Shi's most important contributions are, first of all, his demonstration of a revolutionary epi-layer structure for avalanche photodiode (APD) and high-power photodiodes (PD). By inserting additional field control layers inside the multiplication layers of ultra-fast APDs, the burden imposed by the tremendous increase of the dark current for pursuing high-speed performance can be released with a simultaneous improvement in their sensitivity. This novel APD structure has since been put into mass production by Source photonic, Hisilicon Optoelectronics, and LandMark Optoelectronics with a further 2 dB enhancement of the sensitivity achieved as compared to that of other state-of-the-art APD products for **10G passive optical network (PON) market**. On the other hand, in the traditional millimeter-wave (MMW)/THz PD, the output power is usually limited by its low optimum bias voltage ($< -1V$). He has shown how, by inserting an additional field control layer inside the epi-structure of a high-power PD, the device can sustain an overshoot electron drift-velocity under a high bias, allowing an unprecedented increase in the THz/MMW output power, which allows the realization of an MMW photonic system with enough output power for practical applications. On the other hand, Prof. Shi is one of the pioneering leaders in the field of single-mode VCSEL research. He is the co-inventor of Zn-diffusion VCSEL and is the first to demonstrate Zn-diffusion VCSELS with a record-high single-mode power and high-speed performance for sensing and data communication. Compared with other reported technologies for single-mode VCSELS, the Zn-diffusion VCSEL technology is the only one which can simultaneously deliver high single-mode power and reduce its resistance. He has transferred his Zn-diffusion VCSEL structure to Unikorn Semiconductor in mass production for light source in the **proximity sensor module in the Apple iPhone** due to that it can effectively reduce the resistance of ion-implanted VCSEL to meet the requirement of high-reliability. In addition to Zn-diffusion technique discussed above, Prof. Shi was the first to demonstrate oxide-relief structures which could greatly reduce the parasitic capacitance in VCSELS. In comparison to the other reported techniques, such as multi-oxide layers, oxide-relief is the only one which can simultaneously improve both speed and reliability performance. He has transferred this VCSEL structure to the industry, such as Source Photonic, Unikorn Semiconductor, and AboCom communications for mass production of **short-reach data communication VCSEL transmitter**.

Publications Authored and co-authored 178 SCI journal papers, 2 book editor, 6 invited book chapters, over 134 international conference papers, 30 U.S.A. patents, 30 Taiwan patents, 6 invited magazine reports, and several invited international conference papers.

Awards & Honors

Invited speaker in IEEE/OSA OFC 2011
 Invited speaker in IEEE IPC (formerly LEOS) 2012, 2017, 2021
 Invited speaker in Plastic Optical Fiber (POF) Conference 2012
 Invited magazine report in Compound Semiconductor 2012
 Invited magazine report in SPIE Newsroom 2007, 2013, and 2017
 Invited speaker in SPIE Photonic West 2015, 2017, and 2022
 Invited speaker in JASP Autumn meeting at 2016
 Invited speaker in ICO-24 2017
 Invited speaker in PIERS 2018
 Invited speaker in MOC 2025
 2007 CIEE Young Research Award
 2007, 2009-2013 Outstanding Research Awards at National Central University
 2013 till now Distinguished Professor at National Central University
 OFC Technical Program Committee (From 2009-2011)
 SSDM Technical Program Committee (2012)
 MWP Technical Program Committee (2012)
 CLEO-PR Technical Program Committee (2013)
 IPRM Technical Program Committee (2014)
 OECC Technical Program Committee (2014-2016, 2022)

2010 國科會吳大猷獎 (Outstanding Young Research Award at National Science Council of Taiwan)

2012 IEEE Senior Member

World's top 2% scientists list by Stanford University (2021-2023); Over 6280 google citations to publications; H-index= 43
 Associate editor of *Optics Express* (2017-2023)
 Guest editor-in-chief of the *Optics Express* special issue of "Photonic Technologies for Autonomous Cars" (2019)
 Guest editor for the 2018 *IEEE Journal of Selected Topics in Quantum Electronics (JSTQE)*, their special issue about optical detectors.

VCSEL work to be selected as cover page of 2022 *IEEE JSTQE special issue on semiconductor laser*

2021 科技部未來科技獎

2024 國科會產學計畫特優獎

2023 Optica (formerly OSA) Fellow with the following citation: "for contributions to ultrafast photodiodes and high-speed VCSELs for optics fiber communications"

2025 IEEE Fellow with the following citation: "for contributions to high-speed photodetectors and VCSELs for optics fiber communications"

Selective Journal Publications of Prof. Jin-Wei Shi: (*corresponding author)

(2025)

1. Cheng-Wei Lin, Zhe-Wei Hsu, Jian-Wei Tung, Xin Chen, Chia-Hsuan Wang, Dong Hao, Jia-Liang Yen, J.-J. Liu, Ming-Jun Li, and **Jin-Wei Shi***, "Single-Mode VCSELs With Zn-Diffusion Apertures for Applications in Co-Packaged Optics Systems," in *IEEE Journal of Selected Topics in Quantum Electronics*, vol. 31, no. 2: Pwr. and Effic. Scaling in Semiconductor Lasers, pp. 1-9, March-April 2025, Art no. 1501409, doi: 10.1109/JSTQE.2024.3454318.
2. Yen-Kun Wu, Chao-Chuan Kuo, Pei-Syuan Lin, Sean Yang, H.-S. Chen, Jack Jia-Sheng Huang, and **Jin-Wei Shi***, "Thinning of Cascaded Multiplication Layers in Avalanche Photodiodes for High-Speed and High-Power-Tolerant Performance," in *Journal of Lightwave Technology*, vol. 43, no. 2, pp. 690-700, Jan., 2025.

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3. Y. -C. Huang, N. -W. Chen, Y. -K. Wu, Naseem and **J. -W. Shi***, "Improvements in the Maximum THz Output Power and Responsivity in Near-Ballistic Uni-Traveling-Carrier Photodiodes With an Undercut Collector," in *Journal of Lightwave Technology*, vol. 42, no. 7, pp. 2362-2370, 1 April, 2024, doi: 10.1109/JLT.2023.3340502.
4. Yu-Kuan Tsai, Zheng-Xiang Liao, Yu-Xiang Lin, H.-S. Chen, Jack Jia-Sheng Huang, Pei-Hsun Wang, Chia-Chien Wei, You-Chia Chang, Yung Hung, and **Jin-Wei Shi**, "Linearization of wavelength sweeping lasers for the construction of 4-D FMCW LiDAR images of slow-moving objects using baseband beat note signals," *Opt. Express*, vol. 32, pp. 20401-20411, May, 2024.
5. Yan-Chieh Chang, Ye-Kun Wu, Chia-Chien Wei, You-Chia Chang, Tzyy-Sheng Horng, and **Jin-Wei Shi***, "Window size dependence of gain and bandwidth in avalanche photodiodes with multiple multiplication layers under near Geiger-mode operation," *Opt. Express*, vol. 32, pp. 24744-24755, July, 2024.
6. Yi-Shan Lee, Tzu-Yang Chen, Yu-Ju Chen, Wei-Hong Kan, Xue-Wen Liu, and **Jin-Wei Shi**, "Photon-Number-Resolving Detection with Highly Efficient InGaAs/InAlAs Single-Photon Avalanche Diode," *Photonics*, vol. 11, no. 8, pp. 724, Aug., 2024. <https://doi.org/10.3390/photonics11080724>

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7. Chi-Wai Chow, You-Chia Chang, Sheng-I Kuo, Pin-Cheng Kuo, Ju-Wei Wang, Yin-He Jian, Zohaiddin Ahmad, Po-Han Fu, **Jin-Wei Shi**, Ding-Wei Huang, Tun-Yao Hung, Yuan-Zeng Lin, Chien-Hung Yeh, Yang Liu, "Actively Controllable Beam Steering Optical Wireless Communication (OWC) Using Integrated Optical Phased Array (OPA)," *Journal of Lightwave Technology*, vol. 41, no. 4, pp. 1122-1128, 15 Feb. 15, 2023, doi: 10.1109/JLT.2022.3206843.
8. Naseem, Nan-Wei Chen, Syed Hasan Parvez, Zohaiddin Ahmad, Sean Yang, H-S Chen, Hsiang-Szu Chang, Jack Jia-Sheng Huang, and **Jin-Wei Shi***, "Simultaneous enhancement of the bandwidth and responsivity in high-speed avalanche photodiodes with an optimized flip-chip bonding package," *Opt. Express* vol. 31, pp. 26463-26473, July, 2023.
9. **Jin-Wei Shi***, T.-C. Lu, F. Koyama, "Nanophotonics Pioneer: Prof. Dr. Dieter Bimberg "Green Photonic Network: From VCSELS to Nanophotonics". *Photonics*, vol. 10, pp. 976, Sep., 2023. <https://doi.org/10.3390/photonics10090976>
10. Zuhaib Khan, Min-Long Wu, Cheng-Wei Lin, Cheng-Chun Chen, Chia-Jui Chang, Tien- Chang Lu, Nikolay Ledentsov Jr., Nikolay Ledentsov and **Jin-Wei Shi*** "Miniaturized Vertical-Cavity Surface-Emitting Laser Array with a Novel Electrode Design for High-Speed, Low-Noise, and High-Brightness Performance," *Advanced Photonics Research*, vol. 4, pp. 2370022, Sep., 2023.
11. Yu-Xiang Lin, Zohaiddin Ahmad, Sung-Yi Ou, Wei-Chih Su, Yan-Chieh Chang, Naseem, Jye-Hong Chen, Yung-Jr Hung, You-Chia Chang, Chia-Chien Wei, Tzyy-Sheng Horng, and **Jin-Wei Shi***, "A 4-D FMCW LiDAR With Ultra-High Velocity Sensitivity," in *Journal of Lightwave Technology*, vol. 41, no. 21, pp. 6664-6674, 1 Nov.1, 2023, doi: 10.1109/JLT.2023.3292139.

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12. Cheng-Yi Liu, Chun-Kai Huang, Yen-Yu Huang, Kun-Chieh Chang, Kun-Lin Yu, Chien-Hung Chiang, Chun-Guey Wu, Shih-Chang Lee, Wei-Yu Yen, Jinn-Kong Sheu, and **Jin-Wei Shi***, "Flexible multijunction solar cells embedded inside smart dust modules for outdoor applications to Smart Grids," *Applied Energy*, vol. 306, Part A, pp. 117970, Jan., 2022.
13. Y.-C. Zhao, Z. Ahmad, W.-M. Long, Z. Khan, N. Ledentsov Jr., M.- B. Sanayeh, T.-L. Pan, C.-C. Chen, C.-J. Chang, T.-C. Lu, N. N. Ledentsov and **J.-W. Shi***, "Separated Electrodes for the Enhancement of High-Speed Data Transmission in Quasi-Single- Mode Vertical-Cavity Surface-Emitting Laser Arrays" *Optics Express*, vol. 30, no. 15, pp. 26690-26700, Jul. 2022.
14. Sheng-I Kuo, Ju-Wei Wang, Zohaiddin Ahmad, Po-Han Fu, Hsin-Hung Lin, **Jin-Wei Shi**, Ding-Wei Huang, and You-Chia Chang, "Reconfigurable scan lens based on an actively controlled optical phased array," *Opt. Lett.* 47, 3676-3679 (2022)
15. Jie-Chen Shih, Zuhaib Khan, Yung-Hao Chang, and **Jin-Wei Shi***, "High-Brightness VCSEL Arrays with Inter-Mesa Waveguides for the Enhancement of Efficiency and High-Speed Data Transmission," *IEEE Journal of Selected Topics in Quantum Electronics* vol. 28, no. 1, pp. 1-11, Jan.-Feb. 2022.
16. Zuhaib Khan, Yong-Hao Chang, Te-Lieh Pan, Yaung-Cheng Zhao, Yen-Yu Huang, Chia-Hung Lee, Jui-Sheng Chang, Cheng-Yi Liu, Cheng-Yuan Lee, Chao-Yi Fang, and **Jin-Wei Shi***, "High-Brightness, High-Speed, and Low-Noise VCSEL Arrays for Optical Wireless Communication," in *IEEE Access*, vol. 10, pp. 2303-2317, 2022, doi: 10.1109/ACCESS.2021.3133436.
17. Zohaiddin Ahmad, Sheng-I Kuo, You-Chia Chang, Rui-Lin Chao, Naseem, Yi-Shan Lee, Yung-Jr Hung, Huang-Ming Chen, Jyehong Chen, Chee Seong Goh, and **Jin-Wei Shi*** "Avalanche Photodiodes with Dual Multiplication Layers and Ultra-High Responsivity-Bandwidth Products for FMCW Lidar System Applications," *IEEE Journal of Selected Topics in Quantum Electronics* vol. 28, no. 2, pp. 1-9, March-April 2022, Art no. 3800709, doi: 10.1109/JSTQE.2021.3062637. **(Invited Paper)**
18. Yi-Shan Lee, Yan-Min Liao, Ping-Li Wu, Chi-En Chen, Yu-Jie Teng, Yu-Ying Hung and **Jin-Wei Shi***, "In_{0.52}Al_{0.48}As Based Single Photon Avalanche Diodes with Stepped E-field in Multiplication Layers and High Efficiency Beyond 60 %," *IEEE Journal of Selected Topics in Quantum Electronics*, vol. 28, no. 2, pp. 1-7, March-April 2022, Art no. 3802107, doi: 10.1109/JSTQE.2021.3114130.
19. Naseem, Zohaiddin Ahmad, Yan-Min Liao, Po-Shun Wang, Sean Yang, Sheng-Yun Wang, Hsiang-Szu Chang, H.-S. Chen, Jack Jia-Sheng Huang, Emin Chou, Yu-Heng Jan, and **Jin-Wei Shi***, "Avalanche Photodiodes with Composite Charge-Layers for Low Dark Current, High-Speed, and High-Power Performance," *IEEE Journal of Selected Topics in Quantum Electronics*, vol. 28, no. 2, pp. 1-10, March-April, 2022, Art no. 3801910, doi: 10.1109/JSTQE.2021.3111895.
20. **J.-W. Shi***, A. Beling, N. Nishiyama, "Special Issue on Advanced Ultra-High Speed Optoelectronic Devices," *Photonics* vol. 9, pp. 312, May, 2022. <https://doi.org/10.3390/photonics9050312>.

21. Yen-Yu Huang, Yung-Hao Chang, Yaung-Cheng Zhao, Zuhair Khan, Zohauddin Ahmad, Chia-Hung Lee, Jui-Sheng Chang, Cheng-Yi Liu, and **Jin-Wei Shi***, "Low-Noise, Single-Polarized, and High-Speed Vertical-Cavity Surface-Emitting Lasers for Very Short Reach Data Communication," *IEEE/OSA Journal of Lightwave Technology*, vol. 40, no. 12, pp. 3845-3854, June, 2022.
22. Z. Ahmad, P.-S. Wang, Naseem, Y.-C. Huang, Y.-C. Chang, Y.-C. Chang, Y.-S. Lee, and **Jin-Wei Shi*** "Avalanche photodiodes with multiple multiplication layers for coherent detection," *Sci Rep*, vol. vol. 12, pp. 16541, Oct., 2022. <https://doi.org/10.1038/s41598-022-21041-6>.
23. Nasseem, Po-Shun Wang, Zohauddin Ahmad, Syed Hasan Parvez, Sean Yang, H.-S. Chen, Hsiang-Szu Chang, Jack Jia-Sheng Huang, and **Jin-Wei Shi***, "Top-Illuminated Avalanche Photodiodes With Cascaded Multiplication Layers for High-Speed and Wide Dynamic Range Performance," in *Journal of Lightwave Technology*, vol. 40, no. 24, pp. 7893-7900, 15 Dec.15, 2022, doi: 10.1109/JLT.2022.3204743.

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24. Bohao Liu, Suparna Seshadri, Jihh-Min Wun, Nathan P. O'Malley, Daniel E. Leaird, Nan-Wei Chen, **Jin-Wei Shi**, and Andrew M. Weiner, "W-Band Photonic Pulse Compression Radar with Dual Transmission Mode Beamforming," *IEEE/OSA Journal of Lightwave Technology*, vol. 39, no. 6, pp. 1619-1628, March, 2021, doi: 10.1109/JLT.2020.3038846.
25. Y. -S. Lee, Naseem, P. -L. Wu, Y. -J. Chen and **J. -W. Shi**, "Neat Temporal Performance of InGaAs/InAlAs Single Photon Avalanche Diode With Stepwise Electric Field in Multiplication Layers," in *IEEE Access*, vol. 9, pp. 32979-32985, Feb., 2021, doi: 10.1109/ACCESS.2021.3060824.
26. Zohauddin Ahmad, Yan-Min Liao, Sheng-I Kuo, You-Chia Chang, Rui-Lin Chao, Naseem, Yi-Shan Lee, Yung-Jr Hung, Huang-Ming Chen, Jyehong Chen, Jiun-In Guo, and **Jin-Wei Shi***, "High-Power and High-Responsivity Avalanche Photodiodes for Self-Heterodyne FMCW Lidar System Applications," in *IEEE Access*, vol. 9, pp. 85661-85671, June, 2021.
27. Naseem, Z. Ahmad, Y.-M. Liao, R.-L. Chao, P.-S. Wang, Y.-S. Lee, S. Yang, S.-Y. Wang, H.-S. Chang, H.-S. Chen, J. J.-S. Huang, E. Chou, Y.-H. Jan, and **J.-W. Shi***, "Avalanche Photodiodes with Dual Multiplication Layers for High-Speed and Wide Dynamic Range Performances," *Photonics*, vol. 8, no. 4, p. 98, Mar. 2021. **(Invited Paper)**

28. R. -L. Chao, Z. Ahmad, J. Chen, Y. Lai, Y. -J. Hung and **J. -W. Shi***, "Microring Optical Phase-Shifters With Low Driving-Voltage, Low Insertion Loss, and Small Residual Amplitude Modulation," in *Journal of Lightwave Technology*, vol. 39, no. 24, pp. 7740-7747, 15 Dec.15, 2021, doi: 10.1109/JLT.2021.3098347.

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29. Zuhair Khan, Jie-Chen Shih, Rui-Lin Chao, Tzong-Liang Tsai, Hsin-Chuan Wang, Gang-Wei Fan, Yu-Chen Lin, **Jin-Wei Shi***, "High-Brightness and High-Speed Vertical-Cavity Surface-Emitting Laser Arrays," *Optica*, vol. 7, no. 4, pp. 267-275, April, 2020.
30. Rui-Lin Chao, Z. Ahmad, J. Chen, Y. Lai and **Jin-Wei Shi***, "BJT-Type Optical Phase Shifter with Small Power Consumption and Fast Response Time on a Silicon Photonics Foundry Platform," in *IEEE Journal of Selected Topics in Quantum Electronics*, vol. 26, no. 2, pp. 1-7, March-April 2020, Art no. 8301107.
31. Zuhair Khan, N. Ledenstov Jr., L. Chorchos, Jie-Chen Shih, Yung-Hao Chang, N.N. Ledenstov, and **Jin-Wei Shi***, "Single-Mode 940 nm VCSELs with Narrow Divergence Angles and High-Power Performances for Fiber and Free-Space Optical Communications," *IEEE Access*, vol. 8, pp. 72095-72101, 2020.
32. R. L. Chao, Z. Ahmad, J. Chen, Y. Lai and **J.-W. Shi***, "Three-Port Optical Phase-Shifters and Modulators with Ultra-High Modulation Efficiency, Positive RF-Linking Gain, and Low Residual Amplitude Modulation," in *IEEE Access*, vol. 8, pp. 80836-80841, 2020.
33. **Jin-Wei Shi***, Zuhair Khan, Ray-Hua Horng, Hsiao-Yun Yeh, Chun-Kai Huang, Cheng-Yi Liu, Jie-Chen Shih, Yung-Hao Chang, Jia-Liang Yen, and Jinn-Kong Sheu, "High-power and single-mode VCSEL arrays with single-polarized outputs by using package-induced tensile strain," *Optics Letters*, vol. 45, No. 17, pp. 4839-4842, Sep., 2020.
34. Po-Chou Pan, Dhiman Nag, Zuhair Khan, Ching-Jung Chen, **Jin-Wei Shi**, Apurba Laha, and Ray-Hua Horng, "Effect of Thermal Management on the Performance of VCSELs," *IEEE Transactions on Electron Devices*, vol. 67, no. 9, pp. 3736-3739, Sept. 2020.

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35. Fu-Bang Chen, Kai-Lun Chi, Wei-Yu Yen, Jinn-Kong Sheu, Ming-Lun Lee, and **Jin-Wei Shi**, "Investigation on Modulation Speed of Photon-recycling White Light-emitting Diodes with Vertical-conduction Structure" *IEEE/OSA Journal of Lightwave Technology*, vol. 37, pp. 1225-1230, Feb., 2019.
36. Naseem, Zohauddin Ahmad, Rui-Lin Chao, Hsiang-Szu Chang, C.-J. Ni, H.-S. Chen, Jack Jia-Sheng Huang, Emin Chou, Yu-Heng Jan, and **Jin-Wei Shi***, "The enhancement in speed and responsivity of uni-traveling

- carrier photodiodes with GaAs_{0.5}Sb_{0.5}/In_{0.53}Ga_{0.47}As type-II hybrid absorbers," *Optics Express*, vol. 27, no. 11, pp. 15495-15504, May, 2019.
37. **Jin-Wei Shi***, Jiun-In Guo, Manabu Kagami, Paul Suni, and Olaf Ziemann, "Photonic technologies for autonomous cars: feature introduction," *Optics Express* vol. 27, pp. 7627-7628, March, 2019. (SCI)
 38. N. Ledentsov Jr., M. Agustin, V.A. Shchukin, J.-R. Kropp, N.N. Ledentsov, Ł. Chorchos, J.P. Turkiewicz, Z. Khan, C.-L. Cheng, **J.-W. Shi**, N. Cherkashin, "Quantum dot 850 nm VCSELs with extreme high temperature stability operating at bit rates up to 25 Gbit/s at 150 °C," *Solid State Electronics*, vol. 155, pp. 150-158, March, 2019. (SCI)
 39. Fan Jun Wei, Richard A. Mole, Sunil K. Karna, **Jin-Wei Shi**, Jinn-Kong Sheu, and Kung-Hsuan Lin, "Verification of complex acoustic mismatch model in sub-THz regime," *Appl. Phys. Lett.*, vol. 114, pp. 151106, April, 2019. (SCI)
 40. Chen-Lung Cheng, N. Ledentsov Jr., Zuhaib Khan, Jia-Liang Yen, N. N. Ledentsov, and **Jin-Wei Shi***, "Ultrafast Zn-Diffusion and Oxide-Relief 940 nm Vertical-Cavity Surface-Emitting Lasers under High-Temperature Operation," *IEEE J. of Sel. Topics in Quantum Electronics*, vol. 25, pp. 1700507, Nov./Dec., 2019.
 41. Hao-Yi Zhao, Naseem, Andrew H. Jones, Rui-Lin Chao, Zohauddin Ahmad, Joe C. Campbell, and **Jin-Wei Shi***, "High-Speed Avalanche Photodiodes with Wide Dynamic Range Performance," *Journal of Lightwave Technology*, vol. 37, no. 23, pp. 5945-5952, 1 Dec.1, 2019.

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42. Yi-Han Chen, Jih-Min Wun, Song-Lin Wu, Rui-Lin Chao, Jack Jia-Sheng Huang, Yu-Heng Jan, H.-S. Chen, C.-J. Ni, Hsiang-Szu Chang, Emin Chou, and **Jin-Wei Shi***, "Top-Illuminated In_{0.52}Al_{0.48}As-Based Avalanche Photodiode with Dual Charge Layers for High-Speed and Low Dark Current Performances," *IEEE J. of Sel. Topics in Quantum Electronics*, vol. 24, No. 2, pp. 3800208, March/April., 2018.
43. J.-M. Wun, Y.-W. Wang, and **J.-W. Shi***, "Ultra-Fast Uni-Traveling Carrier Photodiodes with GaAs_{0.5}Sb_{0.5}/In_{0.53}Ga_{0.47}As Type-II Hybrid Absorbers for High-Power Operation at THz Frequencies," *IEEE J. of Sel. Topics in Quantum Electronics*, vol. 24, No. 2, pp. 8500207, March/April, 2018.
44. N. N. Ledentsov, V. A. Shchukin, V. P. Kalosha, N. N. Ledentsov Jr., J.-R. Kropp, M. Augustin, Ł. Chorchos, J. P. Turkiewicz, and **J.-W. Shi**, "Anti-waveguiding vertical-cavity surface-emitting laser at 850 nm: From concept to advances in high-speed data transmission," *Optics Express*, vol. 26, pp. 445-453, Jan., 2018.
45. N. Ledentsov Jr., M. Agustin, J.-R. Kropp, V. A. Shchukin, V. P. Kalosha, K. L. Chi, Z. Khan, **J.-W. Shi**, N. N. Ledentsov "Temperature stable oxide-confined 850 nm VCSELs operating at bit rates up to 25 Gbit/s at 150°C," *Proc. SPIE, Vertical-Cavity Surface Emitting Lasers XXII*, pp. 10552-24, Feb., 2018.
46. M. Agustin, N. Ledentsov Jr., J.-R. Kropp, V.A. Shchukin, V. P. Kalosha, K. L. Chi, **J.-W. Shi**, N. N. Ledentsov, "50 Gb/s NRZ data transmission over OM5 fiber in the SWDM wavelength range," *Proc. SPIE, Vertical-Cavity Surface Emitting Lasers XXII*, pp. 10552-1, Feb., 2018.
47. Rui-Lin Chao, Linjun Liang, **Jin-Wei Shi**, Tin Komljenovic, Jared Hulme, M. J. Kennedy, and J. E. Bowers, "Fully Integrated Photonic Millimeter-Wave Tracking Generators on the Heterogeneous III-V/Si Platform" *IEEE Photon. Technol. Lett.*, vol. 30, no. 10, pp. 919-922, May, 2018.
48. Nan-Wei Chen, Jih-Min Wun, Hao-Chen Wang, Rui-Lin Chao, Chris Koh, C. H. Dreyfus and **Jin-Wei Shi***, "Design and Analysis of Waveguide-Coupled Photonic THz Transmitters with an Extremely Wide Fractional Bandwidth," *IEEE/OSA Journal of Lightwave Technology*, vol. 36, pp. 4235-4242, Oct., 2018. (Special Issue on Microwave Photonics)
49. Song-Lin Wu, Naseem, Jih-Min Wun, Rui-Lin Chao, Jack Jia-Sheng Huang, N.-W. Wang, Yu-Heng Jan, H.-S. Chen, C.-J. Ni, Hsiang-Szu Chang, Emin Chou, and **Jin-Wei Shi***, "High-Speed In_{0.52}Al_{0.48}As Based Avalanche Photodiode with Top-Illuminated Design for 100 Gbit/sec ER-4 System," *IEEE/OSA Journal of Lightwave Technology*, vol. 36, pp. 5505-5510, Dec., 2018.
50. Zuhaib Khan, Jia-Liang Yen, Chen-Lung Cheng, Kai-Lun Chi, and **Jin-Wei Shi***, "Enhancing the Static and Dynamic Performance of High-Speed VCSELs by Zn-Diffused Shallow Surface Relief Apertures," *IEEE J. of Quantum Electronics*, vol. 54, pp. 2400706, Oct., 2018.

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**Intellectual Property for Dual Charge Layers APD: (For 10G PON APD with state-of-the-art SEN)
Transferred to Source Photonics and LandMark Optoelectronics Corporation**



(12) **United States Patent**
Shi

(10) **Patent No.:** **US 9,466,751 B1**
(45) **Date of Patent:** **Oct. 11, 2016**

(54) **AVALANCHE PHOTODIODE HAVING ELECTRIC-FIELD CONFINEMENT BY MESAS**

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(72) Inventor: **Jin-Wei Shi**, Taoyuan (TW)

(73) Assignee: **NATIONAL CENTRAL UNIVERSITY**, Taoyuan (TW)

(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 0 days.

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(21) Appl. No.: **15/060,787**

(22) Filed: **Mar. 4, 2016**

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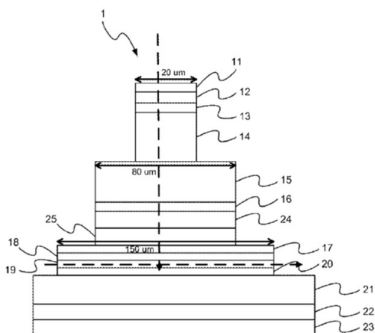
(51) **Int. Cl.**
H01L 31/107 (2006.01)
H01L 31/0224 (2006.01)
H01L 31/0304 (2006.01)

(52) **U.S. Cl.**
CPC **H01L 31/107** (2013.01); **H01L 31/022408** (2013.01); **H01L 31/03046** (2013.01)

(58) **Field of Classification Search**
CPC H01L 31/1075; H01L 31/107; H01L 31/02027
USPC 257/84, 186, 438; 438/34
See application file for complete search history.

(57) **ABSTRACT**
A novel photodetecting device having field confined by mesas is provided. The device is an avalanche photodiode (APD) of indium aluminum arsenide (InAlAs). The device has epitaxial layers with a multiplication layer at bottom as a cathode. Hence, the strongest electric field is confined inside the bottom of the device to avoid surface breakdown. Double mesa is used to confine the electric field of the multiplication layer. Furthermore, a composite multiplication layer with supper thin thickness and wide bandgap is used to reduce the tunneling dark current. Hence, the thickness of equivalent multiplication layer can be reduced to enhance sensitivity.

14 Claims, 6 Drawing Sheets



**Intellectual Property for Zn-diffusion VCSEL: (For proximity sensor module in the Apple iPhone)
Transferred to Unicorn Semiconductor Corporation in Mass Production**

I474569



(19) 中華民國智慧財產局

(12) 發明說明書公告本

(11) 證書號數：TW I474569 B

(45) 公告日：中華民國 104 (2015) 年 02 月 21 日

(21) 申請案號：101130064

(22) 申請日：中華民國 101 (2012) 年 08 月 16 日

(51) Int. Cl.: H01S5/183 (2006.01)

H01S5/187 (2006.01)

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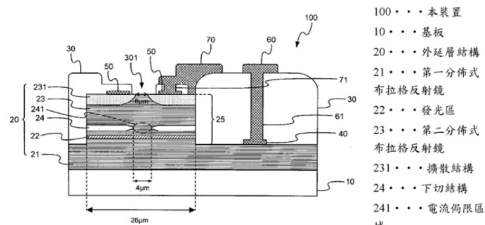
申請專利範圍項數：15 項 圖式數：4 共 24 頁

(54) 名稱

可調控光學模態之垂直共振腔面射型雷射

(57) 摘要

一種可調控光學模態之垂直共振腔面射型雷射，具有經由蝕刻程序沿著側壁處部分去除 VCSEL 之鋁複合層而形成一在發光區上方或下方之下切結構(Undercut Structure)，以及經由修飾擴散製程將分佈式布拉格反射鏡(DBR)頂部中央區域周圍不同組成之多晶層(Multi-Layer)選擇性地呈非序排列(Disorder)為單一組成之單晶層(Single Layer)而形成一低反射率之擴散結構，俾使該分佈式布拉格反射鏡成為可控制光學模態數目之 DBR 反射鏡。因此，具有優越之動態性能，包括低功耗、最大之運轉速度及高資料傳輸速率與功率消耗之比值，可實現極大 D-係數(-13.5 GHz/mA^{1/2})、在 34 Gbit/s 操作之最低能量與資料比率(EDR: 140 fJ/bit)、以及無誤差傳輸在 0.8 公里之 OM4 多模光纖在 25 Gbit/s 操作之最低能量與資料距離比(EDDR: 175.5 fJ/bit.km)。



第 1 圖

- 100 . . . 本裝置
- 10 . . . 基板
- 20 . . . 外延層結構
- 21 . . . 第一分佈式布拉格反射鏡
- 22 . . . 發光區
- 23 . . . 第二分佈式布拉格反射鏡
- 231 . . . 擴散結構
- 24 . . . 下切結構
- 241 . . . 電流局限區域
- 25 . . . 凸型平台式結構
- 30 . . . 隔絕層
- 301 . . . 光源射出孔
- 40 . . . N 型接面
- 50 . . . P 型接面
- 60 . . . N 型金屬電極
- 61 . . . 貫穿孔洞
- 70 . . . P 型金屬電極
- 71 . . . 貫穿孔洞